

## Product Summary

| $V_{(BR)DSS}$ | $R_{DS(on)MAX}$ | $I_D$ |
|---------------|-----------------|-------|
| 250V          | 18.5mΩ@10V      | 80A   |

## Feature

- Excellent gate charge  $\times R_{DS(on)}$  product
- Very low on-resistance  $R_{DS(on)}$

## Application

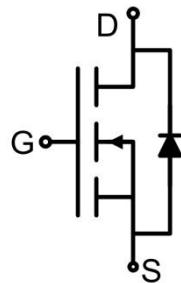
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

## Package

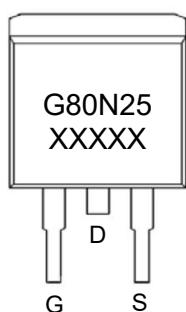


TO-263AB

## Circuit diagram



## Marking



**Absolute Maximum Ratings (T<sub>c</sub>=25°C unless otherwise noted)**

| Parameter   | Symbol                 | Value      | Unit |
|---|------------------------|------------|------|
| Drain-Source Voltage                              | V <sub>DS</sub>        | 250        | V    |
| Gate-Source Voltage                               | V <sub>GS</sub>        | ±20        | V    |
| Continuous Drain Current                          | I <sub>D</sub>         | 80         | A    |
| Continuous Drain Current(T <sub>c</sub> =100°C)   | I <sub>D</sub> (100°C) | 56.6       | A    |
| Pulsed Drain Current                              | I <sub>DM</sub>        | 320        | A    |
| Power Dissipation                                 | P <sub>D</sub>         | 300        | W    |
| Thermal Resistance,Junction-to-Case <sup>1)</sup> | R <sub>θJC</sub>       | 0.5        | °C/W |
| Single pulse avalanche energy <sup>4)</sup>       | E <sub>AS</sub>        | 1200       | mJ   |
| Junction Temperature                              | T <sub>J</sub>         | 150        | °C   |
| Storage Temperature                               | T <sub>STG</sub>       | -55 ~ +150 | °C   |

**Electrical characteristics (T<sub>c</sub>=25 °C unless otherwise noted)**

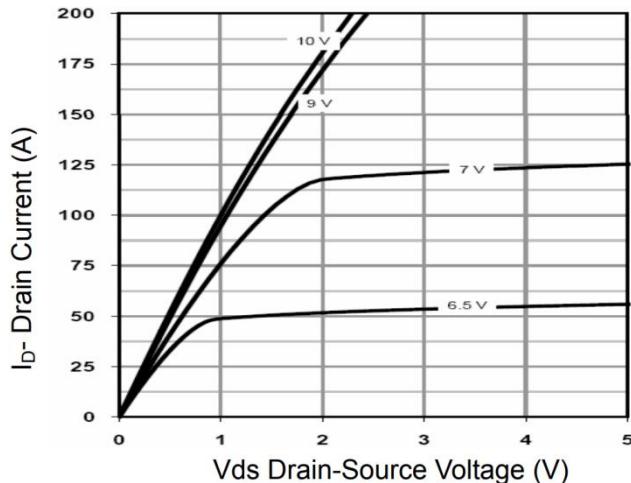
| Parameter                                   | Symbol               | Test Condition  | Min. | Typ. | Max. | Unit |
|---|----------------------|---|------|------|------|------|
| <b>Static Characteristics</b>               |                      |   |      |      |      |      |
| Drain-source breakdown voltage              | V <sub>(BR)DSS</sub> | V <sub>GS</sub> = 0V, I <sub>D</sub> =250μA   | 250  |      |      | V    |
| Zero gate voltage drain current             | I <sub>DSS</sub>     | V <sub>DS</sub> =250V, V <sub>GS</sub> = 0V   |      |      | 1    | μA   |
| Gate-body leakage current                   | I <sub>GSS</sub>     | V <sub>GS</sub> =±20V, V <sub>DS</sub> = 0V   |      |      | ±100 | nA   |
| Gate threshold voltage <sup>2)</sup>        | V <sub>GS(th)</sub>  | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                                | 2.5  | 3.5  | 4.4  | V    |
| Drain-source on-resistance <sup>2)</sup>    | R <sub>DS(on)</sub>  | V <sub>GS</sub> =10V, I <sub>D</sub> =40A   |      | 16   | 18.5 | mΩ   |
| Forward transconductance <sup>2)</sup>      | g <sub>FS</sub>      | V <sub>DS</sub> =10V, I <sub>D</sub> =40A   | 70   |      |      | S    |
| <b>Dynamic characteristics<sup>3)</sup></b> |                      |   |      |      |      |      |
| Input Capacitance                           | C <sub>iss</sub>     | V <sub>DS</sub> =125V, V <sub>GS</sub> =0V,f =1MHz                                      |      | 5400 |      | pF   |
| Output Capacitance                          | C <sub>oss</sub>     |   |      | 329  |      |      |
| Reverse Transfer Capacitance                | C <sub>rss</sub>     |   |      | 12   |      |      |
| Total Gate Charge                           | Q <sub>g</sub>       | V <sub>DS</sub> =125V, V <sub>GS</sub> =10V,I <sub>D</sub> =40A                         |      | 76.7 |      | nC   |
| Gate-Source Charge                          | Q <sub>gs</sub>      |   |      | 22.7 |      |      |
| Gate-Drain Charge                           | Q <sub>gd</sub>      |   |      | 20   |      |      |
| Turn-on delay time                          | t <sub>d(on)</sub>   | V <sub>DD</sub> =125V,V <sub>GS</sub> =10V,<br>I <sub>D</sub> =40A,R <sub>G</sub> =4.7Ω |      | 18   |      | nS   |
| Turn-on rise time                           | t <sub>r</sub>       |   |      | 26   |      |      |
| Turn-off delay time                         | t <sub>d(off)</sub>  |   |      | 41   |      |      |
| Turn-off fall time                          | t <sub>f</sub>       |   |      | 11   |      |      |
| <b>Source-Drain Diode characteristics</b>   |                      |   |      |      |      |      |
| Diode Forward Current <sup>1)</sup>         | I <sub>s</sub>       |   |      |      | 80   | A    |
| Diode Forward voltage <sup>2)</sup>         | V <sub>SD</sub>      | V <sub>GS</sub> =0V, I <sub>s</sub> =80A  |      |      | 1.2  | V    |
| Reverse Recovery Time                       | t <sub>rr</sub>      | T <sub>J</sub> = 25°C, I <sub>F</sub> =40A<br>di/dt = 100A/μs <sup>2)</sup>             |      | 140  |      | nS   |
| Reverse Recovery Charge                     | Q <sub>rr</sub>      |   |      | 600  |      | nC   |

Notes:

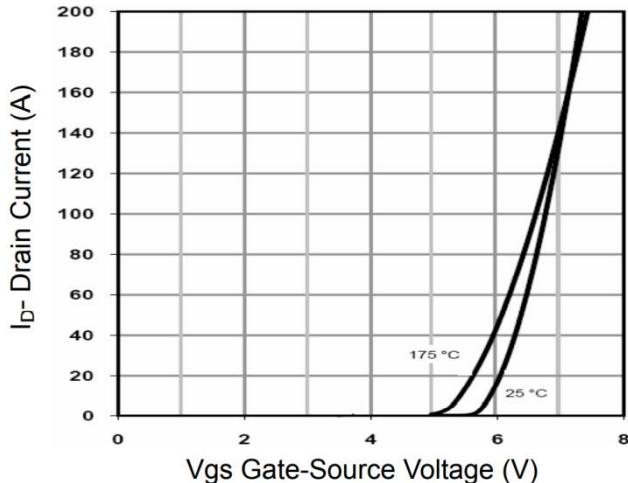
- 1) Surface Mounted on FR4 Board, t ≤ 10 sec.
- 2) Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
- 3) Guaranteed by design, not subject to production.
- 4) EAS condition : T<sub>j</sub>=25 °C,V<sub>DD</sub>=50V,V<sub>G</sub>=10V,L=0.5mH,R<sub>g</sub>=25Ω.



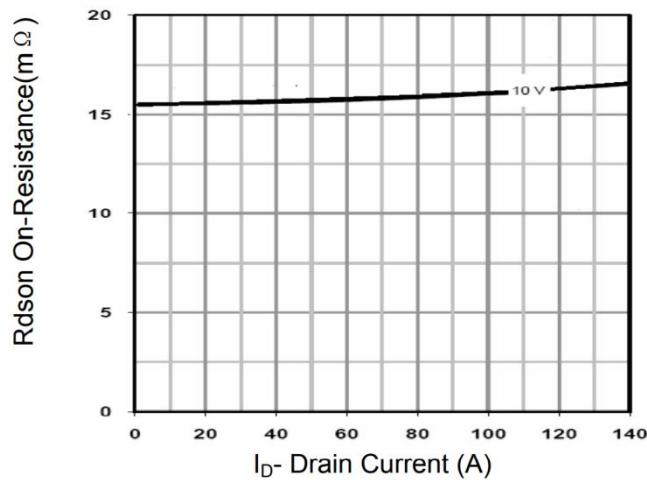
## Typical Characteristics



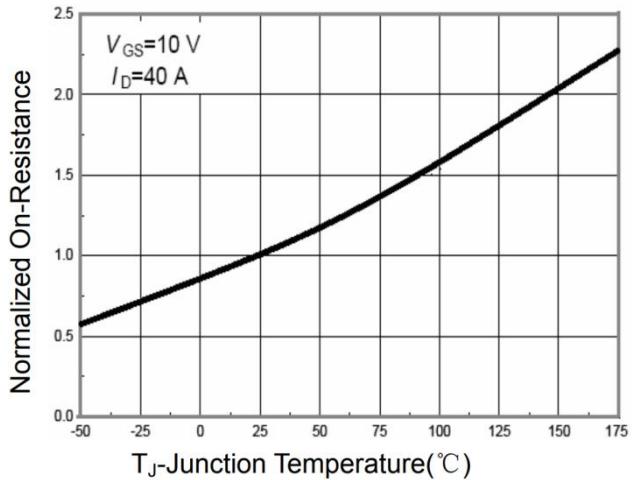
**Figure 1 Output Characteristics**



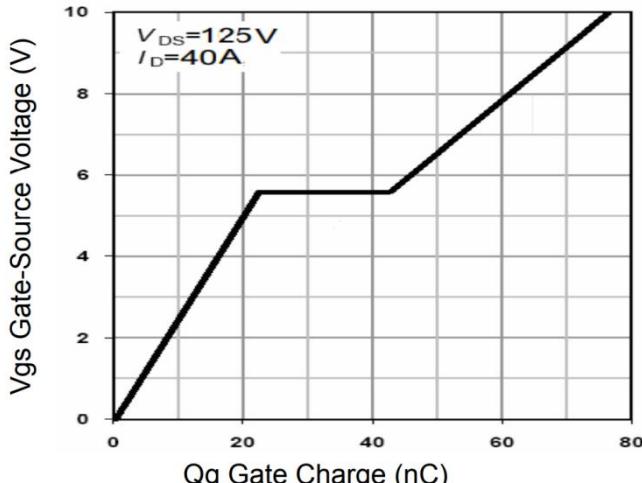
**Figure 2 Transfer Characteristics**



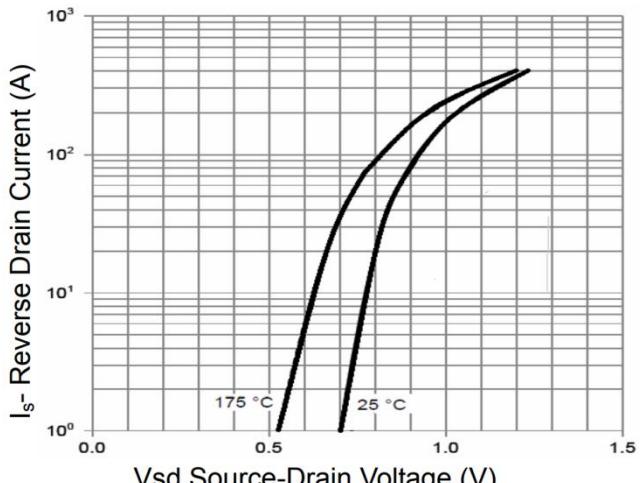
**Figure 3 Rdson- Drain Current**



**Figure 4 Rdson-JunctionTemperature**



**Figure 5 Gate Charge**



**Figure 6 Source- Drain Diode Forward**

## Typical Characteristics

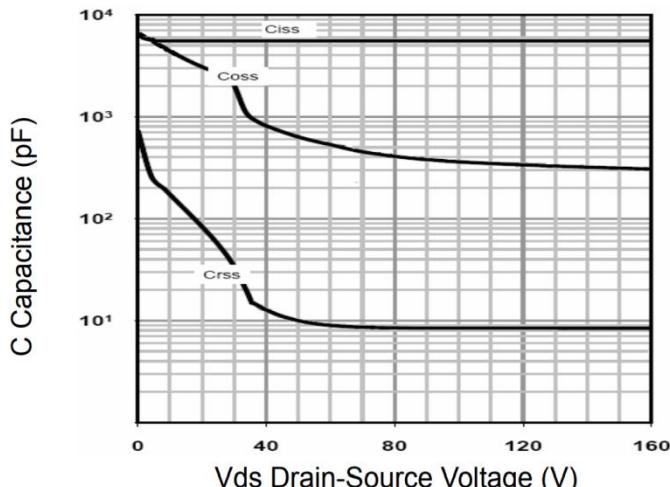


Figure 7 Capacitance vs Vds

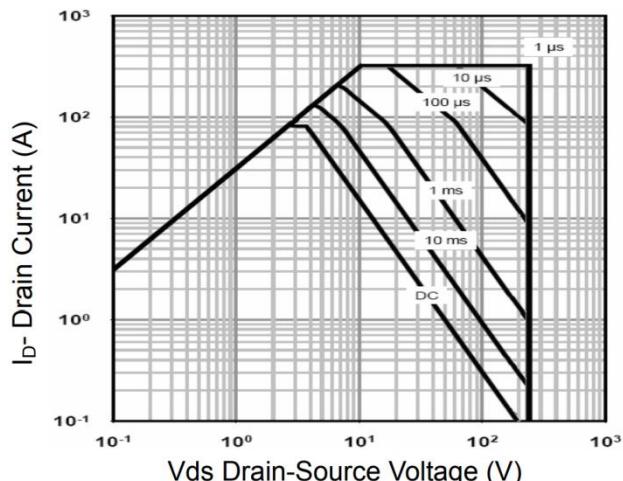


Figure 8 Safe Operation Area

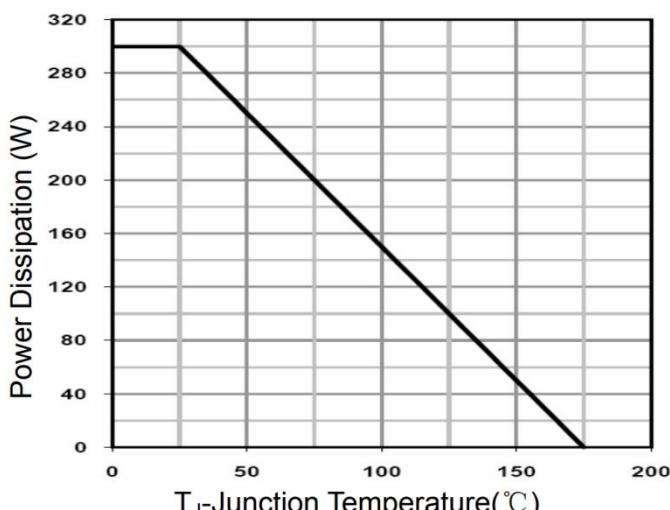


Figure 9 Power De-rating

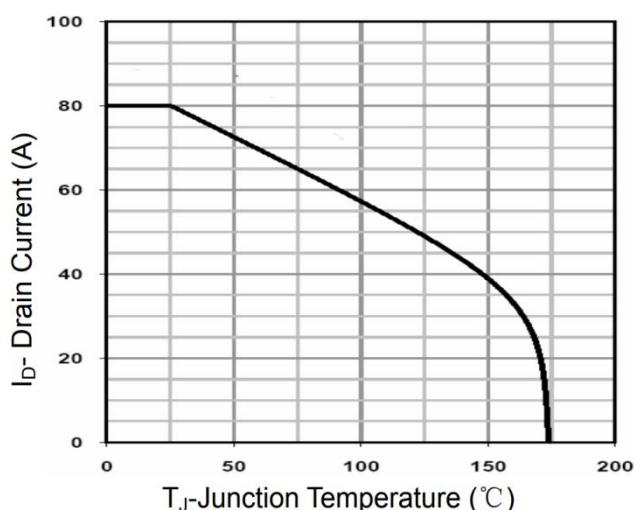


Figure 10 Current De-rating

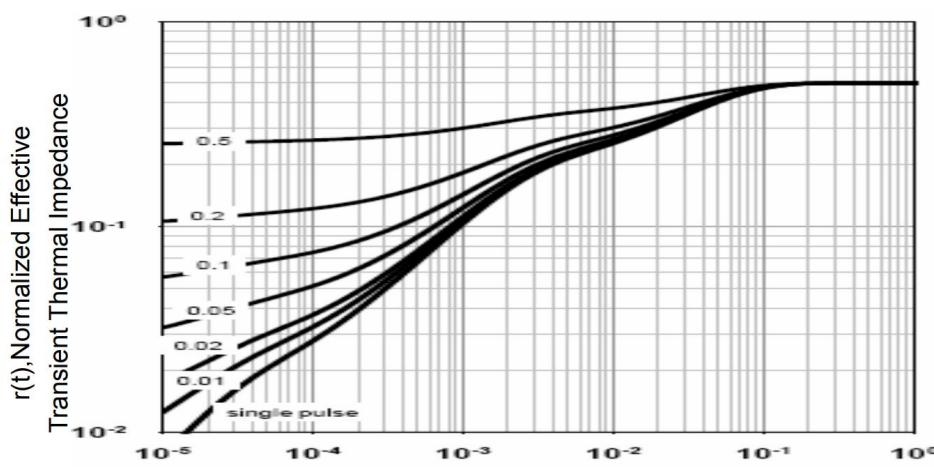
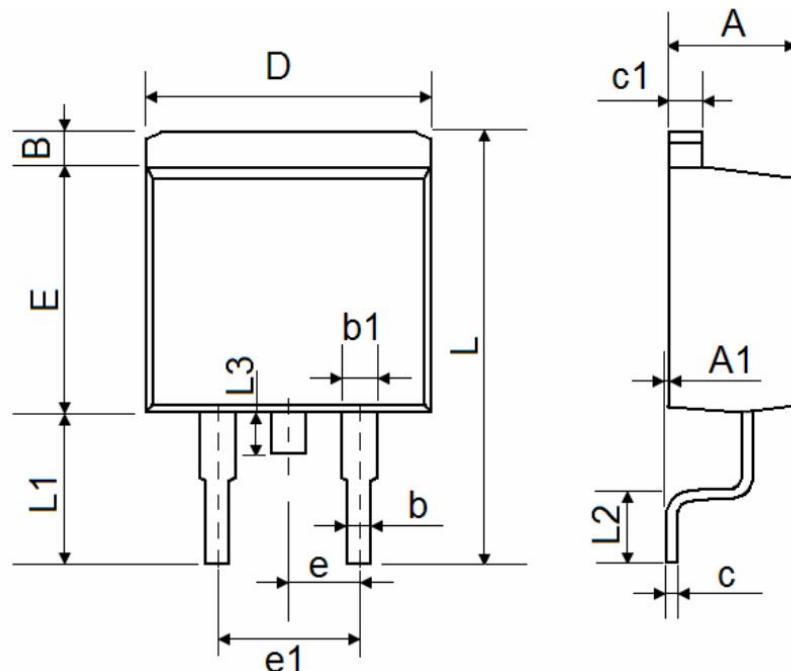


Figure 11 Normalized Maximum Transient Thermal Impedance

## TO-263AB Package Information



| Symbol | Dimensions In Millimeters |        | Dimensions In Inches |       |
|--------|---------------------------|--------|----------------------|-------|
|        | Min.                      | Max.   | Min.                 | Max.  |
| A      | 4.470                     | 4.670  | 0.176                | 0.184 |
| A1     | 0.000                     | 0.150  | 0.000                | 0.006 |
| B      | 1.170                     | 1.370  | 0.046                | 0.054 |
| b      | 0.710                     | 0.910  | 0.028                | 0.036 |
| b1     | 1.170                     | 1.370  | 0.046                | 0.054 |
| c      | 0.310                     | 0.530  | 0.012                | 0.021 |
| c1     | 1.170                     | 1.370  | 0.046                | 0.054 |
| D      | 10.010                    | 10.310 | 0.394                | 0.406 |
| E      | 8.500                     | 8.900  | 0.335                | 0.350 |
| e      | 2.540 TYP.                |        | 0.100 TYP.           |       |
| e1     | 4.980                     | 5.180  | 0.196                | 0.204 |
| L      | 15.050                    | 15.450 | 0.593                | 0.608 |
| L1     | 5.080                     | 5.480  | 0.200                | 0.216 |
| L2     | 2.340                     | 2.740  | 0.092                | 0.108 |
| L3     | 1.300                     | 1.700  | 0.051                | 0.067 |